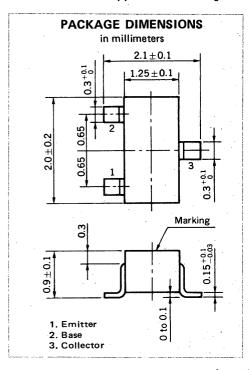


# SILICON TRANSISTOR 2SD2228

## NPN SILICON EPTAXIAL TRANSISTOR AUDIO FREQUENCY AMPLIFIER

#### **DESCRIPTION**

The 2SD2228 is designed for general-purpose applications requiring High DC Current and Low Collector Saturation Voltage. This is suitable for appliances including VCR cameras and headphone stereos.



## **FEATURES**

- High DC Current.
   I<sub>C(DC)</sub> = 500 mA MAX.
- Low Collector Saturation Voltage.
   V<sub>CE(sat)</sub> = 0.1 V MAX. (@I<sub>C</sub> = 100 mA, I<sub>B</sub> = 10 mA)

#### **QUALITY GRADE**

Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

### **ABSOLUTE MAXIMUM RATINGS**

| Maximum Voltage and Currents $(T_a = 2)$ | 25 °C)             |             |     |
|--|--------------------|-------------|-----|
| Collector to Base Voltage                | $V_{\sf CBO}$      | . 25        | V   |
| Collector to Emitter Voltage             | V <sub>CEO</sub>   | 16          | V   |
| Emitter to Base Voltage                  | V <sub>EBO</sub>   | 6           | V   |
| Collector to Base Voltage                | Ic                 | 500         | mΑ  |
| Maximum Power Dissipation                | _                  |             |     |
| Total Power Dissipation                  | -                  |             |     |
| at 25 °C Ambient Temperature             | $P_{T}$            | 150         | mW  |
| Maximum Temperatures                     |                    |             | •   |
| Junction Temperature                     | Ti                 | 150         | ČC. |
| Storage Temperature Range                | $T_{stg}^{\prime}$ | -55 to +150 | °C  |

## ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

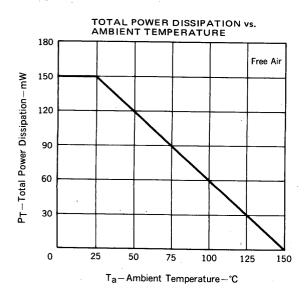
| PARAMETER                    | SYMBOL             | MIN.     | TYP. | MAX. | UNIT | TEST CONDITIONS   |
|------------------------------|--------------------|----------|------|------|------|---|
| Collector Cutoff Current     | ІСВО               | 100,00   |      | 100  | nA   | V <sub>CB</sub> = 16 V, I <sub>E</sub> = 0              |
| Emitter Cutoff Current       | I <sub>EBO</sub>   | *****    |      | 100  | nA   | V <sub>EB</sub> = 6.0 V, I <sub>C</sub> = 0             |
| DC Current Gain              | h <sub>FE1</sub> * | 110      | 200  | 600  | _    | V <sub>CE</sub> = 1.0 V, I <sub>C</sub> = 100 mA        |
| DC Current Gain              | hFE2*              | 100      |      |      | _    | V <sub>CE</sub> = 1.0 V, I <sub>C</sub> = 500 mA        |
| Collector Saturation Voltage | VCE(sat)1 *        |          | 45   | 100  | mV   | I <sub>C</sub> = 100 mA, I <sub>B</sub> = 10 mA         |
| Collector Saturation Voltage | VCE(sat)2 *        |          | 200  | 300  | mV   | I <sub>C</sub> = 500 mA, I <sub>B</sub> = 20 mA         |
| Base to Emitter Voltage      | V <sub>BE</sub> *  | 600      | 650  | 700  | mV   | V <sub>CE</sub> = 1.0 V, I <sub>C</sub> = 10 mA         |
| Gain Bandwidth Product       | f <sub>T</sub>     | 50       |      |      | MHz  | V <sub>CE</sub> = 3.0 V, I <sub>E</sub> = -100 mA       |
| Output Capacitance           | C <sub>ob</sub>    | <u> </u> |      | 15   | pF   | V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1.0 MHz |

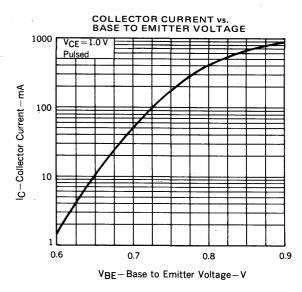
<sup>\*</sup> Pulsed: PW  $\leq$  350  $\mu$ s, Duty Cycle  $\leq$  2 %

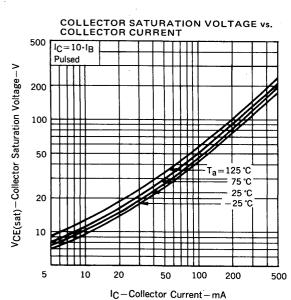
## h<sub>FE</sub> Classification

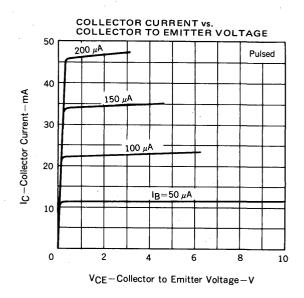
|         |            |            | 544        | 545        |
|---------|------------|------------|------------|------------|
| MARKING | D42        | D43        | D44        | D45        |
| hFE     | 110 to 240 | 190 to 320 | 270 to 400 | 350 to 600 |

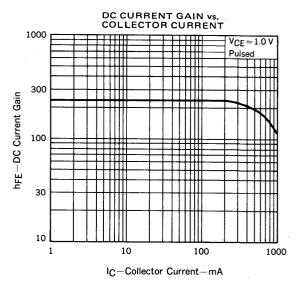
## TYPICAL CHARACTERISTICS (Ta = 25 °C)

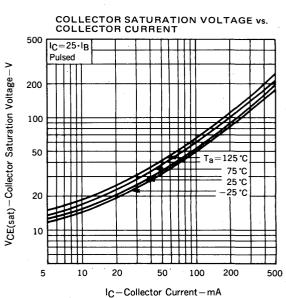


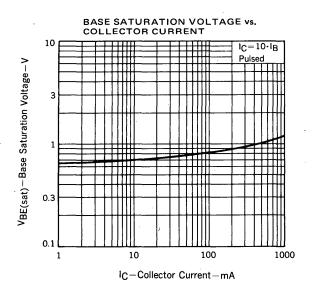


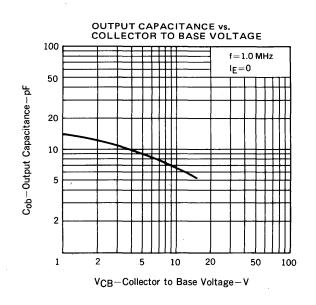












## RECOMMENDED SOLDERING CONDITIONS

Mounting of this product by soldering should be done under the following conditions.

Please consult our representatives about soldering methods and conditions other than these.

## **SURFACE MOUNT TYPE**

For details of the recommended soldering conditions, see the information document "SMT MANUAL" (IEI-1207).

| Soldering Method  | Soldering Conditions   | Symbol for<br>Recommended Conditions |  |
|---|--|--------------------------------------|--|
| Infrared Reflow   | Package peak temp.: 230 °C Soldering time: within 30 sec (above 210 °C) Soldering times: 1, Days limitation: none* | IR30-00                              |  |
| Vapor Phase Soldering   | Package peak temp.: 215 °C Soldering time: within 40 sec (above 200 °C) Soldering times: 1, Days limitation: none* | VP15-00                              |  |
| Soldering bath temp.: below 260 °C  Wave Soldering  Soldering time: within 10 sec  Soldering times: 1, Days limitation: none* |  | WS60-00                              |  |

<sup>\*:</sup> Stored days under storage conditions at 25 °C and below 65 % R.H. after the dry-pack has been opened.

Note 1 Combination of soldering methods should be avoided.

[MEMO]

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Application examples recommended by NEC Corporation

Standard: Data processing and office equipment, Communication equipment (terminal, mobile). Test and Measurement equipment, Audio and Video equipment, Other consumer products, etc.

Special: Automotive and Transportation equipment, Communication equipment (trunk line

Automotive and Transportation equipment, Communication equipment (trunk line), Train and Traffic control devices, industrial robots, Burning control systems, antidisaster systems, anticrime

systems etc.